TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC251AP,TC74HC251AF

8-Channel Multiplexer (3-state)

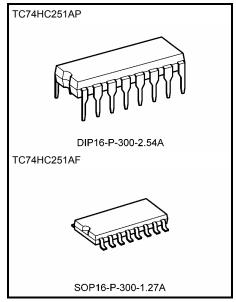
The TC74HC251A is a high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

One of eight date input signals (D0-D7) is selected by decoding of the address input (A, B, C). The selected data appears on two outputs; non-inverting (Y) and inverting (W). When the strobe input is held high, both outputs are in the high-impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

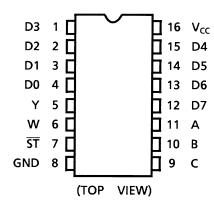
- High speed: $t_{pd} = 15 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays: $t_pLH \simeq t_pHL$
- Wide operating voltage range: VCC (opr) = 2~6 V
- Pin and function compatible with 74LS251



Weight

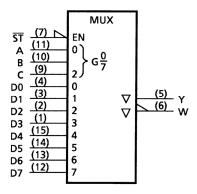
DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.)

Pin Assignment



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IEC Logic Symbol



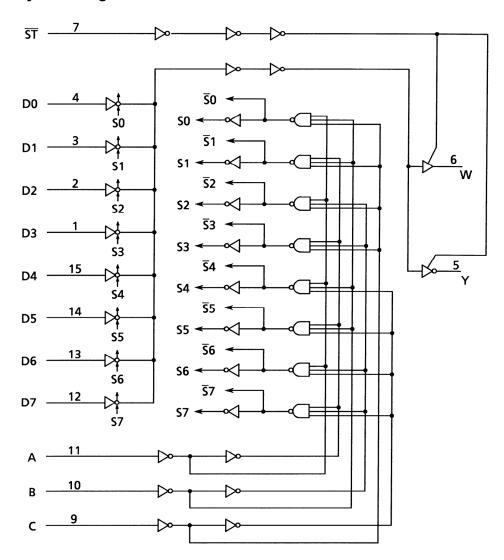
Truth Table

| | lı | Outputs | | | |
|---|--------|---------|--------|----|----------------|
| | Select | | Strobe | | W |
| С | В | Α | ST | Y | VV |
| Х | Х | Х | Н | Z | Z |
| L | L | L | L | D0 | D0 |
| L | L | Н | L | D1 | D ₁ |
| L | Н | L | L | D2 | D ₂ |
| L | Н | Н | L | D3 | D3 |
| Н | L | L | L | D4 | D ₄ |
| Н | L | Н | L | D5 | D̄5 |
| Н | Н | L | L | D6 | D̄6 |
| Н | Н | Н | L | D7 | D7 |

X: Don't care

H: High impedance

System Diagram



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Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|------------------------------|------|
| Supply voltage range | V _{CC} | -0.5~7 | V |
| DC input voltage | V _{IN} | -0.5~V _{CC} + 0.5 | V |
| DC output voltage | V _{OUT} | -0.5~V _{CC} + 0.5 | V |
| Input diode current | I _{IK} | ±20 | mA |
| Output diode current | lok | ±20 | mA |
| DC output current | lout | ±25 | mA |
| DC V _{CC} /ground current | Icc | ±50 | mA |
| Power dissipation | PD | 500 (DIP) (Note 2)/180 (SOP) | mW |
| Storage temperature | T _{stg} | -65~150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of $Ta = -40\sim65$ °C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

| Characteristics | Symbol | Rating | Unit |
|--------------------------|---------------------------------|----------------------------------|------|
| Supply voltage | V _{CC} | 2~6 | V |
| Input voltage | V _{IN} | 0~V _{CC} | ٧ |
| Output voltage | V _{OUT} | 0~V _{CC} | ٧ |
| Operating temperature | T _{opr} | -40~85 | °C |
| | | 0~1000 (V _{CC} = 2.0 V) | |
| Input rise and fall time | t _r , t _f | 0~500 (V _{CC} = 4.5 V) | ns |
| | | 0~400 (V _{CC} = 6.0 V) | |

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

| | | Test Condition V _{CC} (V) | | Ta = 25°C | | | Ta = -40~85°C | | | |
|---------------------------|-----------------|---|----------------------------|-----------|------|------|---------------|------|------|------|
| Characteristics | Symbol | | | | Min | Тур. | Max | Min | Max | Unit |
| | | | | 2.0 | 1.50 | _ | _ | 1.50 | _ | |
| High-level input voltage | V_{IH} | | _ | 4.5 | 3.15 | _ | | 3.15 | _ | V |
| J | | | | 6.0 | 4.20 | _ | _ | 4.20 | _ | |
| | | | | 2.0 | | _ | 0.50 | | 0.50 | |
| Low-level input voltage | V_{IL} | | _ | 4.5 | _ | _ | 1.35 | | 1.35 | V |
| ŭ | | | | 6.0 | _ | _ | 1.80 | _ | 1.80 | |
| | V _{ОН} | VIN = V _{IH} or V _{IL} | | 2.0 | 1.9 | 2.0 | _ | 1.9 | _ | |
| | | | $I_{OH} = -20 \mu A$ | 4.5 | 4.4 | 4.5 | _ | 4.4 | _ | |
| High-level output voltage | | | | 6.0 | 5.9 | 6.0 | | 5.9 | _ | V |
| | | | $I_{OH} = -4 \text{ mA}$ | 4.5 | 4.18 | 4.31 | _ | 4.13 | _ | |
| | | | $I_{OH} = -5.2 \text{ mA}$ | 6.0 | 5.68 | 5.80 | _ | 5.63 | _ | |
| | V _{OL} | V _{IN} = V _{IH} or V _{IL} | | 2.0 | _ | 0.0 | 0.1 | _ | 0.1 | |
| | | | $I_{OL}=20~\mu A$ | 4.5 | _ | 0.0 | 0.1 | | 0.1 | |
| Low-level output voltage | | | | 6.0 | | 0.0 | 0.1 | | 0.1 | V |
| | | | I _{OL} = 4 mA | 4.5 | _ | 0.17 | 0.26 | _ | 0.33 | |
| | | | $I_{OL} = 5.2 \text{ mA}$ | 6.0 | _ | 0.18 | 0.26 | _ | 0.33 | |
| 3-state off leak current | I _{OZ} | V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND | | 6.0 | _ | | ±0.5 | _ | ±5.0 | μΑ |
| Input leakage current | I _{IN} | $V_{IN} = V_{CC}$ or GND | | 6.0 | _ | _ | ±0.1 | _ | ±1.0 | μА |
| Quiescent supply current | Icc | V _{IN} = V _{CC} or GND | | 6.0 | _ | _ | 4.0 | | 40.0 | μА |

AC Characteristics (C $_L$ = 15 pF, V $_{CC}$ = 5 V, Ta = 25 $^{\circ}\text{C},$ input: t_r = t_f = 6 ns)

| Characteristics | Symbol | Test Condition | | Тур. | Max | Unit |
|----------------------------|------------------|----------------|---|------|-----|------|
| Output transition time | t _{TLH} | | | 4 | 8 | ns |
| Output transition time | t _{THL} | _ | | | | 115 |
| Propagation delay time | t _{pLH} | | | 4.4 | 24 | no |
| (D-Y) | t _{pHL} | _ | _ | 14 | 24 | ns |
| Propagation delay time | t _{pLH} | | | 15 | 24 | ns |
| (D-W) | t _{pHL} | _ | | 10 | 24 | 115 |
| Propagation delay time | t _{pLH} | | | 19 | 31 | no |
| (A, B, C-Y) | t _{pHL} | _ | _ | 19 | 31 | ns |
| Propagation delay time | t _{pLH} | | | 19 | 31 | |
| (A, B, C-W) | t _{pHL} | _ | _ | 19 | 31 | ns |
| 2 state output anable time | t _{pZL} | | | 10 | 18 | no |
| 3-state output enable time | t _{pZH} | | | 10 | 18 | ns |



AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

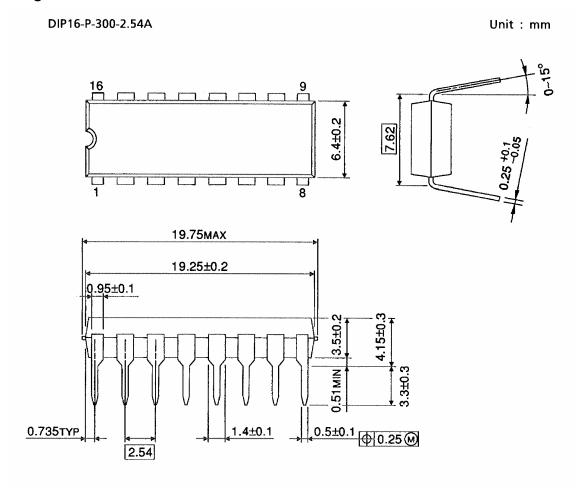
| | | Test Condition | est Condition | | Ta = 25°C | | | Ta = -40~85°C | |
|-------------------------------|------------------------|----------------|---------------------|-----|-----------|-----|-----|---------------|------|
| Characteristics Symbol | | | V _{CC} (V) | Min | Тур. | Max | Min | Max | Unit |
| | + | | 2.0 | _ | 30 | 75 | _ | 95 | |
| Output transition time | t _{TLH} | _ | 4.5 | _ | 8 | 15 | _ | 19 | ns |
| | t _{THL} | | 6.0 | _ | 7 | 13 | _ | 16 | |
| Propagation delay | t _{pLH} | | 2.0 | _ | 65 | 140 | _ | 175 | |
| time | | _ | 4.5 | _ | 17 | 28 | | 35 | ns |
| (D-Y) | t _{pHL} | | 6.0 | _ | 14 | 24 | | 30 | |
| Propagation delay | + | | 2.0 | _ | 70 | 140 | _ | 175 | |
| time | t _{pLH} | _ | 4.5 | _ | 18 | 28 | _ | 35 | ns |
| (D-W) | t _{pHL} | | 6.0 | _ | 15 | 24 | _ | 30 | |
| Propagation delay | + | | 2.0 | _ | 80 | 180 | _ | 225 | |
| time | t _{pLH} | _ | 4.5 | _ | 23 | 36 | _ | 45 | ns |
| (A, B, C-Y) | t _{pHL} | | 6.0 | _ | 19 | 31 | _ | 38 | |
| Propagation delay | 4 | | 2.0 | _ | 80 | 180 | _ | 225 | |
| time | t _{pLH} | _ | 4.5 | _ | 23 | 36 | _ | 45 | ns |
| (A, B, C-W) | t _{pHL} | | 6.0 | _ | 19 | 31 | _ | 38 | |
| | | | 2.0 | _ | 40 | 105 | _ | 130 | |
| 3-state output enable time | t _{pZL} | _ | 4.5 | _ | 13 | 21 | _ | 26 | ns |
| | ^t pZH | | 6.0 | _ | 10 | 19 | _ | 22 | |
| | 4 | | 2.0 | | 25 | 105 | | 130 | |
| 3-state output disable time | t _{pLZ} | _ | 4.5 | _ | 13 | 21 | _ | 26 | ns |
| | t _{pHZ} | | 6.0 | _ | 11 | 19 | _ | 22 | |
| Input capacitance | C _{IN} | | | | 5 | 10 | _ | 10 | pF |
| Power dissipation capacitance | C _{PD} (Note) | _ | | _ | 69 | _ | | _ | pF |

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

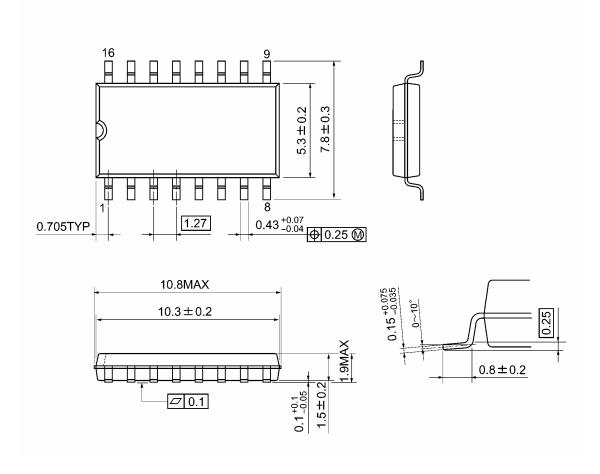
Package Dimensions



Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

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20070701-EN GENERAL

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